Part - A

1. The power rating of a BJT is determined by which of the following
a. Width of the base
b. Heat sink
c. Collector base area
d. Base emitter junction area
2. Which of the following correctly determines the relation between α and β ?
a) $\beta = \alpha/(1-\alpha)$
b) $\alpha = \beta/(1-\alpha)$
c) $\beta = \alpha/(1-\beta)$
d) $\beta = \alpha^*(1-\beta)$
3 region of the transistor is highly doped?
a. Base
b. Collector
c. Both Base and Collector
d. Emitter
4. For common emitter configuration, which of the following is the correct relation?
a) $I_C < I_E$
b) $I_C = \beta I_B$
c) $I_C = \alpha I_E$
d) $I_C = I_E$
5. In a BJT
A. The collector is sandwiched between base and emitter
B. The base region is sandwiched between emitter and collector
C. The emitter region is sandwiched between base and collector
D. the collector is sandwiched between neutral and poles
6. The determination of JFET characteristics necessitates
A. One voltmeter at the output side and ammeters at both sides
B. Ammeter only at the output side and voltmeter only at the input side
C. A voltmeter at the output side and an ammeter at the input side
D. One ammeter at the output side and voltmeters at both sides
ANSWER: D
7. JFET is a controlled device, which has
A. Current, high input impedance

- В. Voltage, low input impedance C. Current, high noise level D. Voltage, high input impedance ANSWER: D 8. The transfer characteristic for a JFET is drawn between ____ and ____ current. A. Input voltage and input current B. Output voltage and input current C. Input voltage and output current D. Output voltage and output current ANSWER: C 9. Which of the following applications, is more suitable for a common gate JFET configuration? A. Audio frequency amplifiers B. High input impedance pre-amplifier stages C. Voltage buffer applications D. Microphone amplifiers ANSWER: D 10, The expression of drain current in CS JFET amplifier is A. $I_D=I_{DSS}*(1-(V_{DS}/V_P))^2$ B. $I_D = I_{DSS} * (1 - (V_{GS}/V_P))^2$ C. $I_D = I_{DSS} * (1 - (V_P/V_{GS}))^2$ D. $I_D=I_{DSS}*(1-(V_P/V_{DS}))^2$ ANSWER: B 11. Which of the following statements are true based on relative comparison between BJT and JFET? (1) JFET has high noise level and better thermal stability (2) Both types of carriers conduct current in JFET A. (1) alone is true B. (2) alone is true
- 12.Transistor works as an amplifier when

ANSWER: D

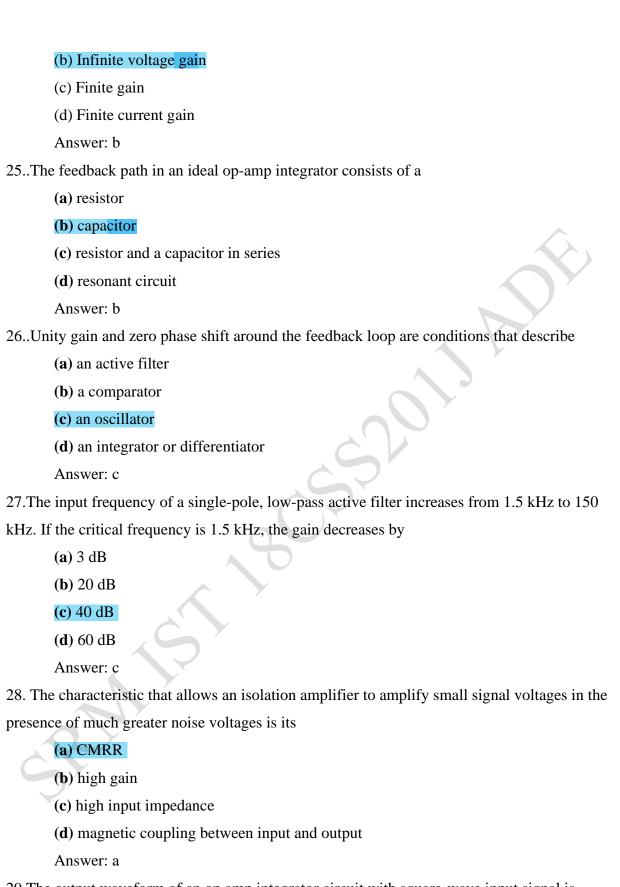
D. Neither (1) nor (2)

C. Both (1) and (2) are true

a. Input junction is forward biased and the output junction is reverse biased

- b. Input junction is reverse biased and the output junction is forward biased
 c. Both input and output junction is forward biased
 d. Both input and output junction is reverse biased
 13. Voltage amplification in the common base is always
 - a. less than 1
 - b. greater than 1
 - c. less than 0
 - d. between 1 to 5
- 14.In CE amplifier the input and output current is
 - a. I_B and I_C
 - b. I_B and I_E
 - c. I_E and I_C
 - d. IE and IC
- 15.An ideal amplifier has
 - a. the noise figure of less than 1 dB
 - b. noise factor of unity
 - c. output S/N more than input S/N
 - d. the noise figure of more than 0 dB.
- 16. The purpose of the Capacitor connected to the input and output side of the amplifier circuit is
 - a. Remove DC component
 - b. Increase input gain
 - c. Increase output gain
 - d. Remove AC component
- 17. The phase difference between the output and input voltages of a CE amplifier is
 - a. 180°
 - b. 0°
 - c. 90°
 - d. 270°
- 18._____ always operates at linear region at all times
 - a. Class B amplifiers
 - b. Class A amplifiers
 - c. Class AB amplifiers
 - d. Class C amplifiers

Ans. B.
19. Which amplifier is designed to handle AC signals?
a. Small signal amplifiers
b. Large signal amplifiers
c. Thin signal amplifiers
d. Band signal amplifiers
Ans. A.
20.An amplifier which gives a theoretical efficiency 0f 70 to 80 % efficiency is
a. Class B amplifiers
b. Class A amplifiers
c. Class AB amplifiers
d. Class C amplifiers
Ans. A
21. Which factor determines the maximum power rating of a transistor?
a. Maximum collector voltage
b. Maximum collector current
c. Temperature of the base to collector junction
d. Temperature of the base to emitter junction
Ans. C
22.Transistor is a in power amplifier.
a. Active device
b. Passive device
c. Op- amp
d. Voltage generating device
Ans. A
23.In power amplifier output power rating will be if the output impedance is
halved.
a. Halved
b. Squared
c. Doubled
d. Square rooted
Ans. B
24. Operational amplifier in open-loop configuration in ideal case has voltage gain
(a) Very large



29. The output waveform of an op amp integrator circuit with square-wave input signal is

- (a) Triangular waveform
- (b) Ramp
- (c) Saw-tooth wave

(d) Spikes

[**Ans.** (a)]

- 30.An op amp circuit that produces an output voltage, which is the sum of its input voltages
 - (a) Summing amplifier
 - (b) Integrator
 - (c) Differentiator
 - (d) Multiplier

[**Ans.** (a)]

- 31. Output of a Schmitt Trigger circuit is a square wave when its input signal is
 - (a) Ramp voltage
 - (b) Sine wave
 - (c) Square wave
 - (d) Triangular wave

[**Ans.** (b)]

- 32. The other name of voltage follower is
 - (a) differential amplifier
 - (b) inverting amplifier
 - (c) non-inverting amplifier
 - (d) unity-gain amplifier

Answer: d

- 33. The function of the feedback sampler in the feedback system is
 - A. mixing the feedback signal with the primary input signal
 - B. taping the output signal for feedback
 - C. to provide the feedback network gain β
 - D. to provide the amplifier gain A

Answer: B

- 34. Which of the following statement is not correct Negative feedback is obtained based on the sign of
 - A. Negative feedback is obtained based on the sign of mixer
 - B. Negative feedback is obtained based on the sign of input signal
 - C. Negative feedback is obtained based on the sign of feedback network gain β
 - D. Negative feedback is obtained based on the sign of amplifier gain A

Answer: B

35.Desensitivity factor of the negative feedback system is

	A. $(-A\beta)$
	B. $(1+A\beta)$
	C. feedback network gain β
	D. amplifier gain A
	Answer: B
36.In v	voltage series feedback amplifier the voltage gain is stabilized to
	A. $(1/\beta)$
	Β. (1+Αβ)
	C. feedback network gain β
	D. amplifier gain A
	Answer: A
37.In c	current shunt feedback system the input resistance with feedback
	A. increases
	B. remain the same
	C. decreases
	D. become zero
	Answer: C
38	oscillations are produced by oscillators
	A. Undamped
	B. Damped
	C. Overdamped
	D. Modulated
	Answer: A
39	feedback is found in oscillators.
	A. Positive
	B. Negative
-	C. Current
	D. Voltage
	Answer: A.
40.The	e temperature coefficient of crystal iswhen the crystal frequency changes due to
change	e in temperature.
	A4
	D 0
	B. 0

D. 4
Answer:C
41.The comparators in the 555 timer circuit
A. compares the output voltages to the internal voltage divider
B. compares the output voltages to the external voltage divider
C. compares the input voltages to the external voltage divider
D. compares the input voltages to the internal voltage divider
Answer: D
42.In 555 timer circuit, thepin is the reset pin.
A. 3
B. 2
C. 4
D. 1
Answer: C
43 For a BJT, for common base configuration the input characteristics is represented by a plot
between which of the following parameters?
a) V _{BE} and I _E
b) V _{BE} and I _B
c) V _{CE} and I _C
d) V_{CC} and I_{C}
44. The drain current of common drain JFET amplifier will increase, when
A. V_{DS} is increased beyond the pinch-off voltage, for a given input voltage
B. The reverse bias voltage V_{GD} is increased
C. The characteristic curve is under saturation or active region.
D. The input voltage is less negative
ANSWER: D
45.In the common source JFET amplifier, when the gate to source voltage is increased from -
3.2V to -4.6V, the drain characteristics will
A. Shift up
B. Shift down
C. Maintain the pinch off voltage constant
D. Decrease the width of depletion layers
ANSWER: B
46.In transistor as amplifier circuit $V_{CE}=V_{CR}+$

a. V _{BI}		
b. 2V _I	BE	
c. 1.5°	$ m V_{BE}$	
d. V _{BE}	z/2	
47 .The prope	r amplification of transistor in d.c load line located at	
a.	The end	
b.	Middle	
c.	Negative axis	
d.	X axis	
48.In common	n, base amplifier configuration, what should be the level of input?	
a.	Low	
b.	High	
c.	Moderate	
d.	Stale	
49. The voltage gain of the following transistor amplifier configuration is lowest		
a.	common collector	
b.	common emitter	
c.	common base	
d.	common emitter & base	
50 .Which of	the following amplifier cannot be used for audio frequency amplification?	
	a. Class A	
	b. Class C	
	c. Class AB	
	d. Class B push-pull	

Ans. B

51. Why class C power amplifier is suitable for tuning circuits?

- a. Due to potential divider
- b. Filter circuit
- c. Audio amplifier
- d. Transformer

Ans. B

52. The problem in which output signal is not an exact reproduction of output signal in		
amplifier is collectively called		
a. Thermal runaway		
b. Phase error		
c. Distortion		
d. Biasing error		
Ans. C		
53 The inductance in the equivalent circuit of crystal oscillator represents a) Inter electrode capacitance b) Compliance c) Viscous factor d) Mass		
54.A relaxation oscillator uses for generating pulses.		
A. Diode		
B. Transistor		
C. Op amp		
D. UJT		
Answer: D		
55. The voltage across the capacitor varies betweenin a 555 timer circuit.		
A. 4 V to 5V		
B. 4.5V to 6 V		
C. 3V to 6 V		
D. 5 V to 8 V		
Answer: C		
56waveforms are generated in UJT relaxation oscillator.		
A. Spikes		
B. Square		
C. Triangular		
D. Saw-tooth		
Answer : A		
57. The following,is not an application of 555 timer.		
A. Sinusoidal		
B. Single pulse generation		
C. Generating train of pulses		

